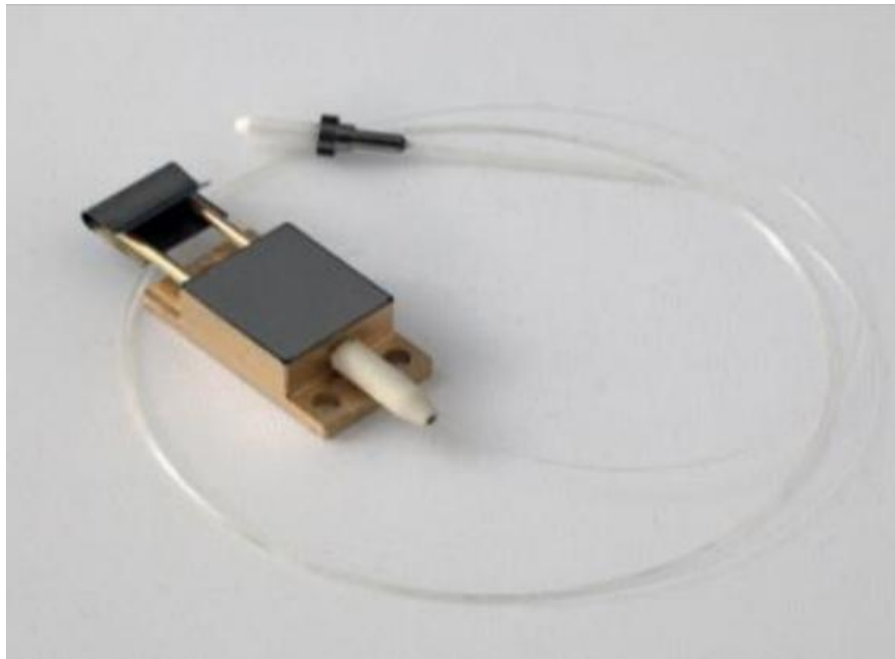


## 1120nm Fiber-Coupled Open Heat Sink High-Power Laser Diode (11W, 400 $\mu\text{m}$ Core)



### ● Product Description

Broad-area laser diodes (also referred to as broad-emitter semiconductor lasers, broad-stripe or broad-emitter laser diodes, single-emitter laser diodes, and high-brightness diode lasers) are edge-emitting laser diodes in which the emission area on the front facet is shaped as a broad stripe. Since the emitter is asymmetric, the beam properties differ in the two orthogonal directions.

## ● Product features

High power output; fiber-coupled design; open high-efficiency heat dissipation; wavelength optional; modular drive

## ● Part Number

MP-FP-1120-11W-SMA

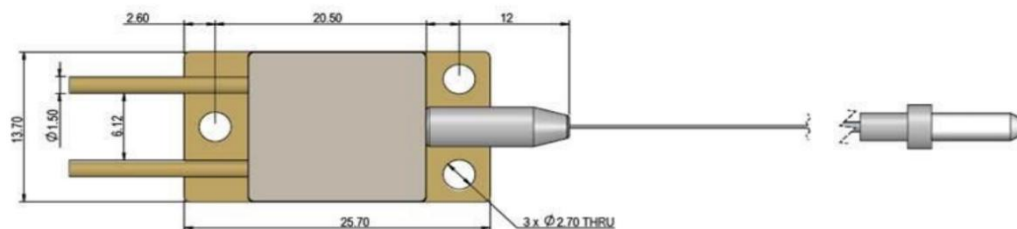
## ● Application area

Industrial Material Processing | Fiber Laser Pumping | Medical Equipment |  
 Scientific Research & Defense | Sensing & Illumination

## ● Core parameters

Central Wavelength	Output Power
1120 nm	>11W

## ● Dimension Drawing





## ● General Parameters

### Specifications

Test Condition: Heat sink temperature 25 °C

Parameter	Symb.	Min.	Typ.	Max.	Unit
Ex-fiber output power	P <sub>out</sub>	3.2	—	—	W
Available wavelength range	$\lambda$	1010	—	1130	nm
Center wavelength tolerance	—	$\lambda-10$	—	$\lambda+10$	nm
Spectral width @ -3 dB level at P <sub>out</sub>	$\Delta\lambda$	—	4	8	nm
Wavelength temperature tunability	$\Delta\lambda/\Delta T$	0.3	0.35	0.4	nm/°C
Threshold current	I <sub>th</sub>	—	0.9	1.3	A
Operating current	I <sub>op</sub>	—	14.5	16.5	A
Forward voltage	V <sub>f</sub>	—	1.45	1.6	V
Recommended operating heat sink temperature	T <sub>op</sub>	20	25	30	°C

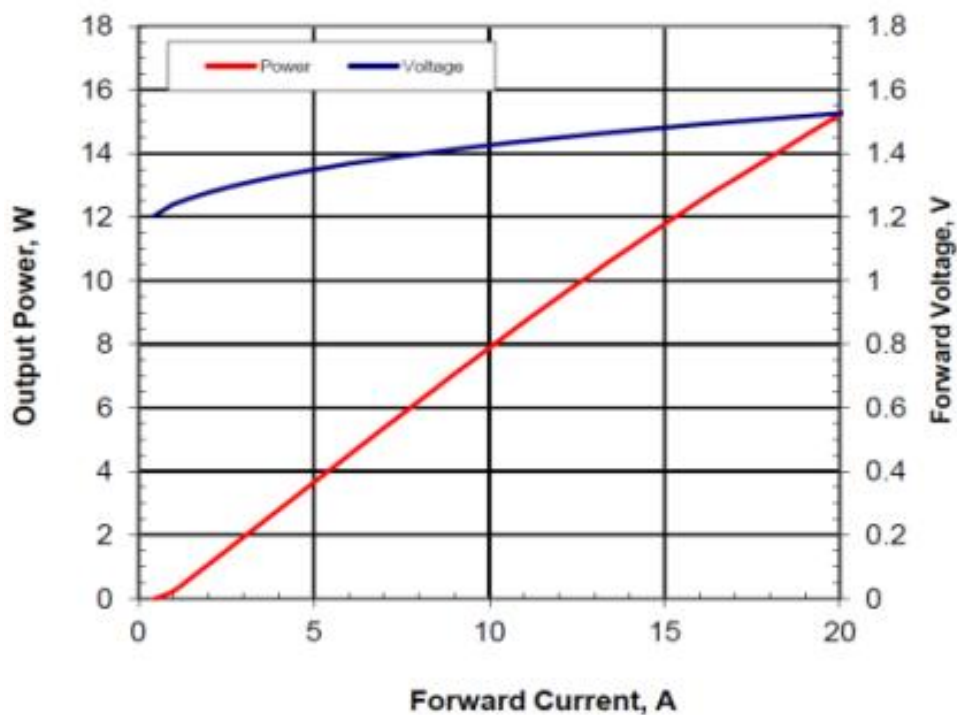
## Typical Performance

\*For reference only

Test Condition: CW operation, heatsink temperature 25 °C

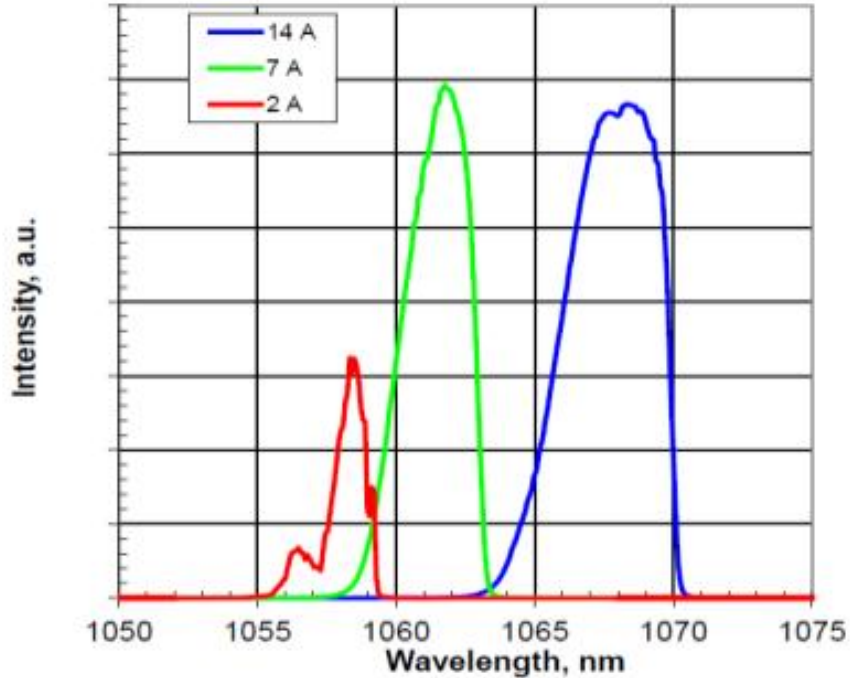
Light Current Voltage Characteristics:

### Light-Current-Voltage Characteristics



**Spectral Characteristics:**

## Spectral Characteristics



\*Performance shown is for a 1064 nm device. Similar performance is expected for other wavelengths within the 1010–1130 nm range.

## Absolute Maximum Ratings

Parameter	Min.	Max.	Unit
Laser Diode Reverse Voltage	—	1	V
Laser Diode CW Forward Current	—	18.0	mA
Storage Temperature Range	5	80	°C



<b>Lead Soldering Temperature (max. 5 s)</b>	—	200	°C
<b>Fiber Bend Radius</b>	3	—	cm
<b>Operating Temperature Range</b>	15	60	°C

## Fiber Specifications

Parameters	Value	Unit
<b>Type</b>	Step index	—
<b>Core diameter</b>	400 ± 5	μm
<b>Cladding diameter</b>	440 ± 5	μm
<b>Buffer diameter</b>	Acrylate, 470 ± 5	μm
<b>Numerical aperture</b>	0.22	—
<b>Length</b>	1.0 ± 0.1	m
<b>Connector</b>	Bare cleaved end, 8° angled ferrule SNZ-3A or SMA905	—